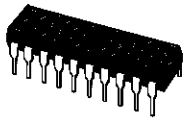
SGS-THOMSON MICROELECTRONICS

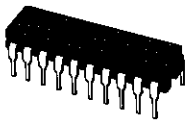
M54HC240HV/241HV
M74HC240HV/241HV

OCTAL BUS BUFFER WITH 3 STATE OUTPUTS
HC240HV: INVERTED - HC241HV NON INVERTED

- HIGH SPEED
  t_{PD} = 12 ns (TYP.) at V_{CC} = 5V
- LOW POWER DISSIPATION
  I_{CC} = 4 µA (MAX.) at T_A = 25 °C
- HIGH NOISE IMMUNITY
  $V_{NIH} = V_{INL}$ = 28 % V_{CC} (MIN.)
- OUTPUT DRIVE CAPABILITY
  15 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
  $|I_{OH}| = I_{OL}$ = 6 mA (MIN)
- BALANCED PROPAGATION DELAYS
  $t_{PLH} = t_{PHL}$
- SAME FUNCTION OF HC240/241 PLUS HIGH TO LOW LEVEL LOGIC CONVERSION CAPABILITY
- LATCH UP FREE OPERATION ALSO WHEN V_{IH} IS HIGHER THAN V_{CC}



B1R
(Plastic Package)



F1R
(Ceramic Package)

M1R
(Micro Package)

ORDER CODES :
M54HCXXXHVF1R M74HCXXXHVM1R
M74HCXXXHVB1R

DESCRIPTION

The M54/74HC240HV and HC241HV are high speed CMOS OCTAL BUS BUFFERs fabricated in silicon gate C^2MOS technology.

They have the same high speed performance of LSTTL combined with true CMOS low power consumption.

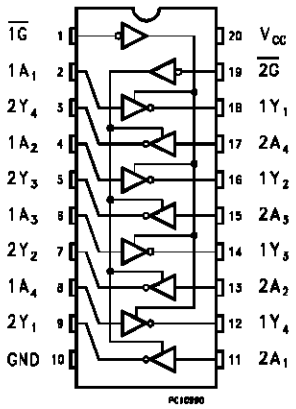
Performing the same function of their non HV counterpart, they have a particularl input configuration which allows all inputs to be driven by logic levels exceeding the supply voltage.

This makes them particularly suitable in systems where mixed 3V/5V logic devices need to be interfaced.

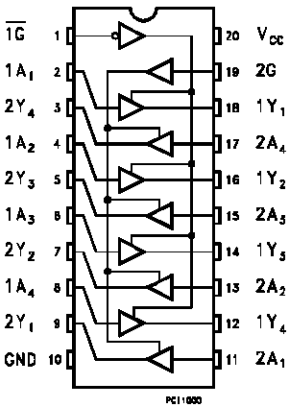
All inputs are equipped with protection circuits against static discharge and transient excess voltage.
NOTE: BOTH DEVICES DO NOT MEET 2KV ESD RATING

PIN CONNECTION (top view)

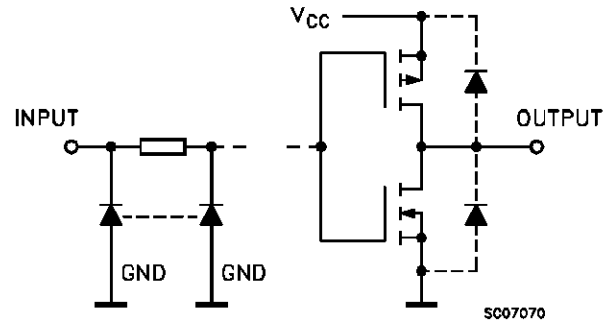
HC240HV



HC241HV



INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION (HC240HV)

PIN No	SYMBOL	NAME AND FUNCTION
1	$\overline{1G}$	Output Enable Input
2, 4, 6, 8	1A1 to 1A4	Data Inputs
9, 7, 5, 3	2Y1 to 2Y4	Data Outputs
11, 13, 15, 17	2A1 to 2A4	Data Inputs
18, 16, 14, 12	1Y1 to 1Y4	Data Outputs
19	$\overline{2G}$	Output Enabel Input
10	GND	Ground (0V)
20	V_{CC}	Positive Supply Voltage

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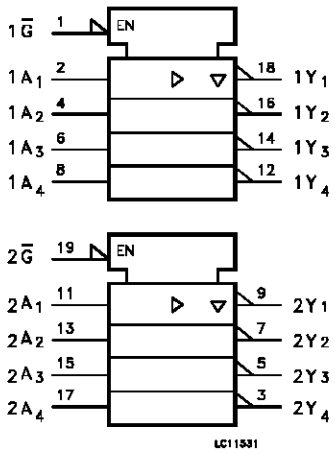
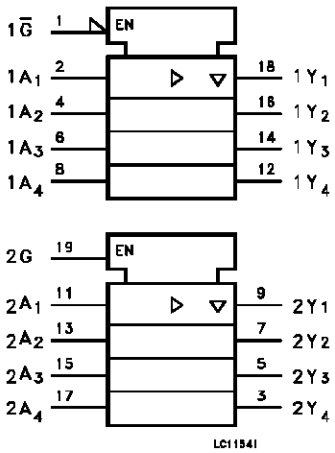
IEC LOGIC SYMBOLS

HC240HV



HC241HV



TRUTH TABLE

INPUT			OUTPUT	
$\overline{G}$	G (HC241)	An	$\overline{Yn}$ (HC240HV)	Yn (HC241HV)
L	H	L	H	L
L	H	H	L	H
H	L	X	Z	Z

X: "H" or "L"
Z: High impedance

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to 13	V
V_I	DC Input Voltage	-0.5 to 13	V
V_O	DC Output Voltage	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	- 20	mA
I_{OK}	DC Output Diode Current	± 100	mA
I_O	DC Output Source Sink Current Per Output Pin	± 35	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 100	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.
(*) 500 mW: ≅ 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Value	Unit
V_{CC}	Supply Voltage		2 to 6	V
V_I	Input Voltage		0 to 12	V
V_O	Output Voltage		0 to V_{CC}	V
T_{op}	Operating Temperature: **M54HC** Series **M74HC** Series		-55 to +125 -40 to +85	°C °C
t_r, t_f	Input Rise and Fall Time	V_{CC} = 2 V	0 to 1000	ns
		V_{CC} = 4.5 V	0 to 500	
		V_{CC} = 6 V	0 to 400	

DC SPECIFICATIONS

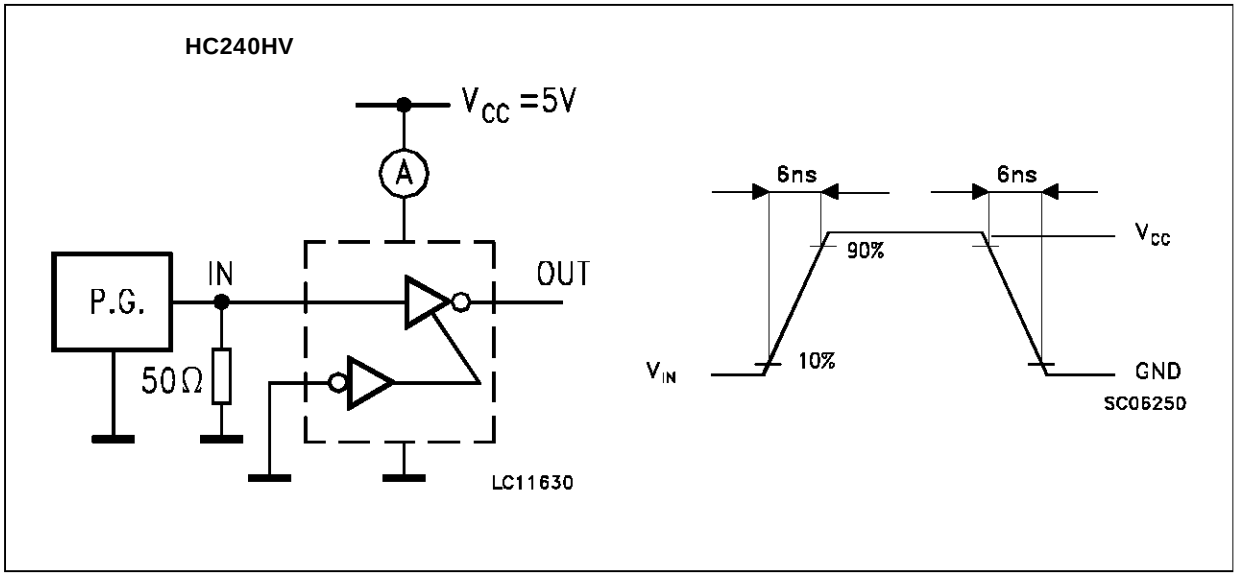
Symbol	Parameter	Test Conditions			Value							Unit
		V_{CC} (V)			T_A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	2.0			1.5			1.5		1.5		V
		4.5			3.15			3.15		3.15		
		6.0			4.2			4.2		4.2		
V_{IL}	Low Level Input Voltage	2.0					0.5		0.5		0.5	V
		4.5					1.35		1.35		1.35	
		6.0					1.8		1.8		1.8	
V_{OH}	High Level Output Voltage	2.0	V_I = V_{IH} or V_{IL}	I_O=-20 µA	1.9	2.0		1.9		1.9		V
		4.5			4.4	4.5		4.4		4.4		
		6.0			5.9	6.0		5.9		5.9		
		4.5		I_O=-6.0 mA	4.18	4.31		4.13		4.10		
		6.0		I_O=-7.8 mA	5.68	5.8		5.63		5.60		
V_{OL}	Low Level Output Voltage	2.0	V_I = V_{IH} or V_{IL}	I_O= 20 µA		0.0	0.1		0.1		0.1	V
		4.5				0.0	0.1		0.1		0.1	
		6.0				0.0	0.1		0.1		0.1	
		4.5		I_O= 6.0 mA		0.17	0.26		0.33		0.40	
		6.0		I_O= 7.8 mA		0.18	0.26		0.33		0.40	
I_I	Input Leakage Current	12.0	V_I = V_{CC} or GND				±0.1		±1		±1	µA
I_{IH}	Input Leakage Current	2.0	V_I = 12 V				±0.1		±1		±1	µA
I_{OZ}	3 State Output Off State Current	12.0	V_I = V_{IH} or V_{IL} V_O = V_{CC} or GND				±0.5		±5		±10	µA
I_{CC}	Quiescent Supply Current	12.0	V_I = V_{CC} or GND				8		80		160	µA

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, Input $t_r = t_f$ = 6 ns)

Symbol	Parameter	Test Conditions			Value							Unit
		V_{CC} (V)	C_L (pF)		T_A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{TLH} t_{THL}	Output Transition Time	2.0	50			25	60		75		90	ns
		4.5				7	12		19		18	
		6.0				6	10		13		15	
t_{PLH} t_{PHL}	Propagation Delay Time	2.0	50			40	110		140		165	ns
		4.5				13	22		28		33	
		6.0				11	19		24		28	
		2.0	150			52	135		170		205	ns
		4.5				17	27		34		41	
		6.0				14	23		29		35	
t_{PZL} t_{PZH}	Output Enable Time	2.0	50	R_L = 1KΩ		52	135		170		205	ns
		4.5				17	27		34		41	
		6.0				14	23		29		35	
		2.0	150	R_L = 1KΩ		63	165		205		250	ns
		4.5				21	33		41		50	
		6.0				18	28		35		43	
t_{PLZ} t_{PHZ}	Output Disable Time	2.0	50	R_L = 1KΩ		40	135		170		205	ns
		4.5				19	27		34		41	
		6.0				15	23		29		35	
C_{IN}	Input Capacitance					5	10		10		10	pF
C_{OUT}	Output Capacitance					10						pF
C_{PD} (*)	Power Dissipation Capacitance					33						pF

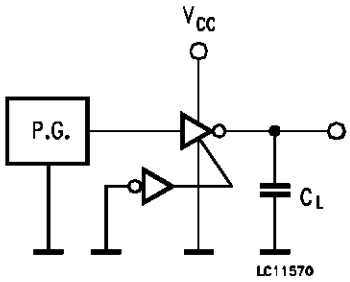
(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operting current can be obtained by the following equation. $I_{CC}(opr) = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}/8$ (per circuit)

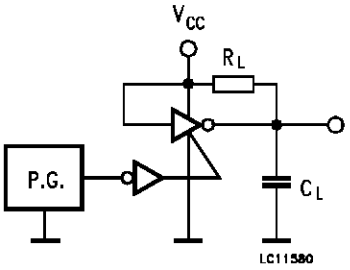
TEST CIRCUIT I_{CC} (Opr.)

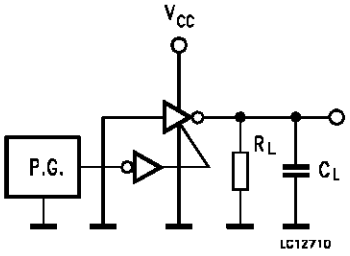


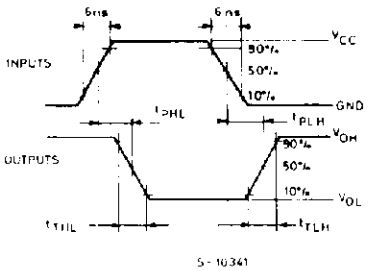
SWITCHING CHARACTERISTICS TEST CIRCUIT

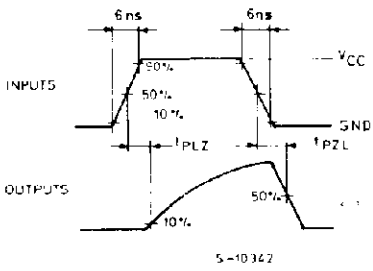
HC240HV

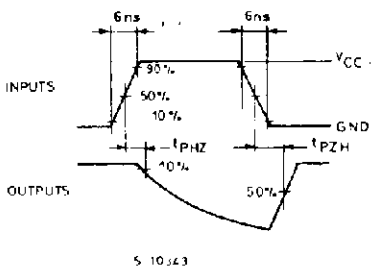




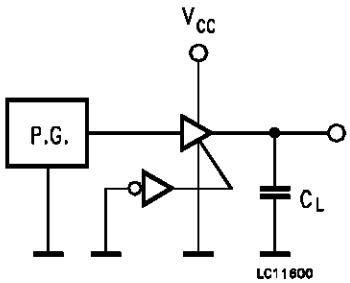


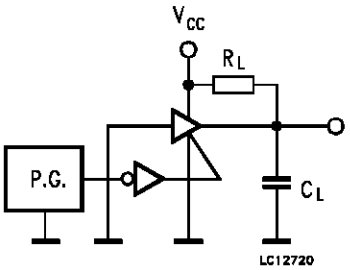


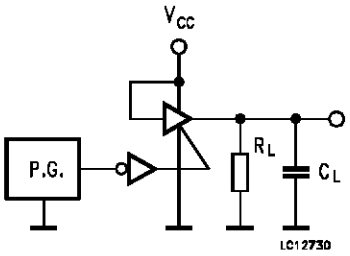


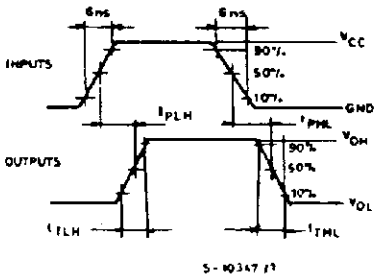


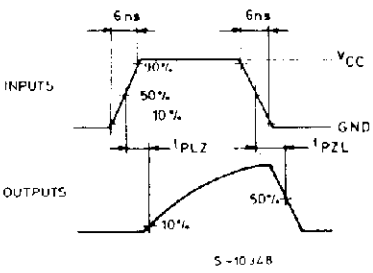
HC241HV

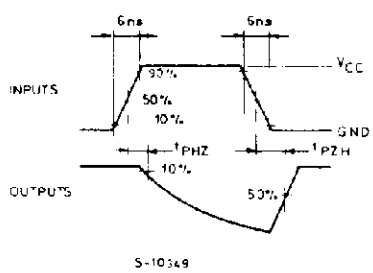






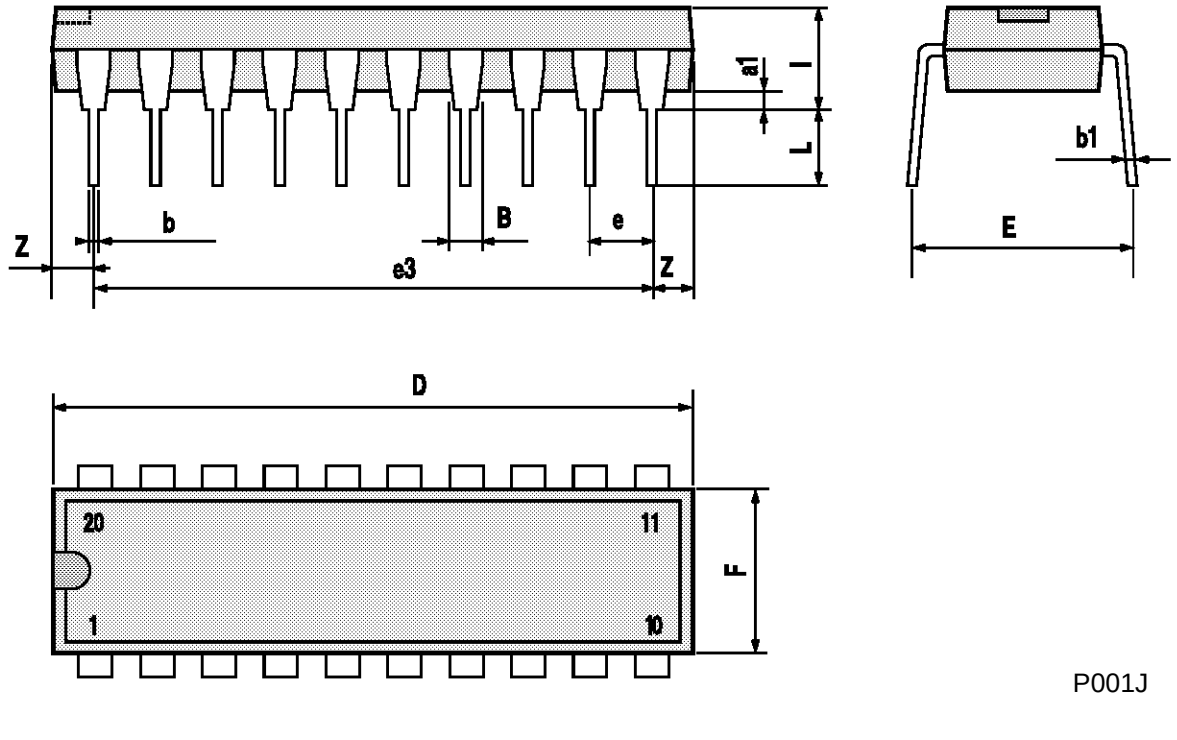






Plastic DIP20 (0.25) MECHANICAL DATA

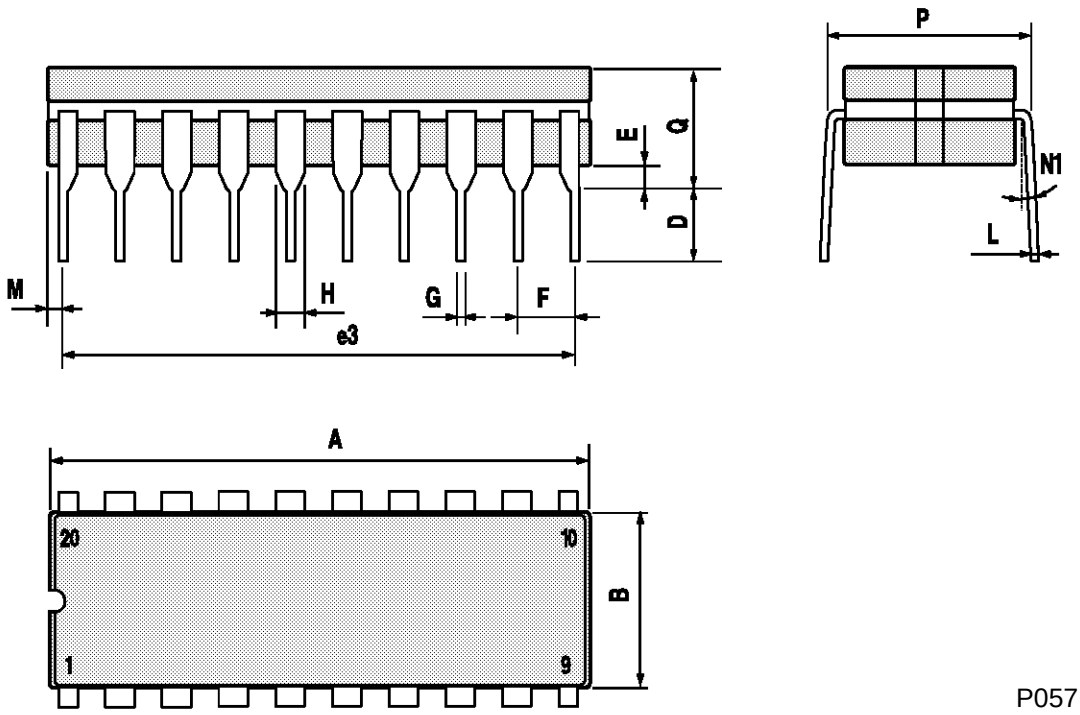
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.254			0.010		
B	1.39		1.65	0.055		0.065
b		0.45			0.018	
b1		0.25			0.010	
D			25.4			1.000
E		8.5			0.335	
e		2.54			0.100	
e3		22.86			0.900	
F			7.1			0.280
I			3.93			0.155
L		3.3			0.130	
Z			1.34			0.053



P001J

Ceramic DIP20 MECHANICAL DATA

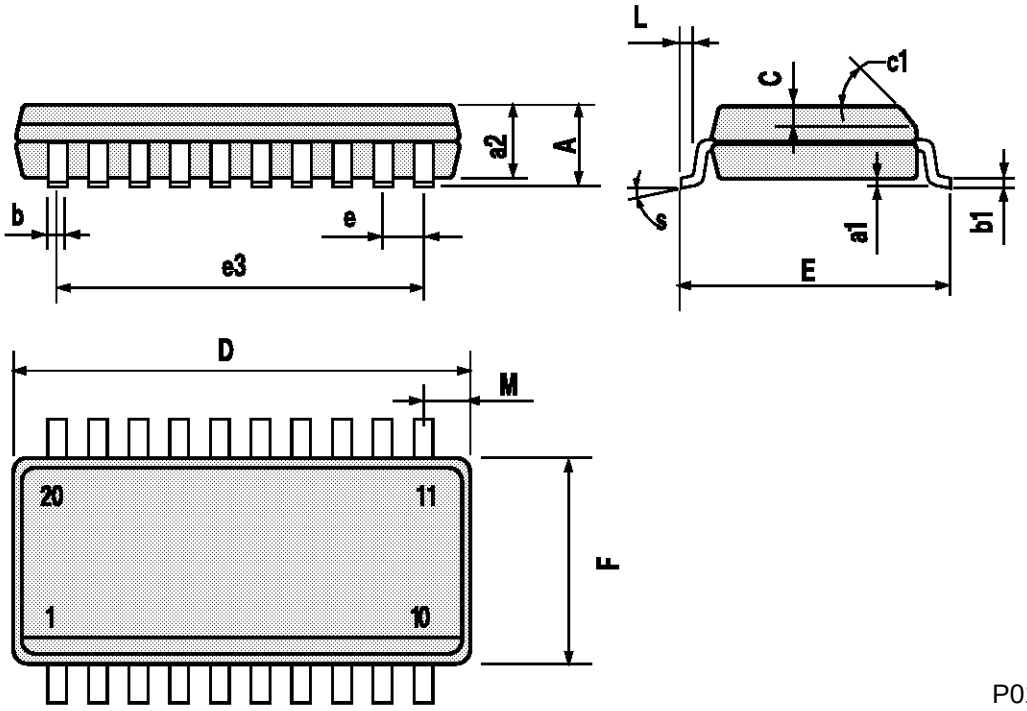
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			25			0.984
B			7.8			0.307
D		3.3			0.130	
E	0.5		1.78	0.020		0.070
e3		22.86			0.900	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
I	1.27		1.52	0.050		0.060
L	0.22		0.31	0.009		0.012
M	0.51		1.27	0.020		0.050
N1	4° (min.), 15° (max.)					
P	7.9		8.13	0.311		0.320
Q			5.71			0.225



P057H

SO20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			2.65			0.104
a1	0.10		0.20	0.004		0.007
a2			2.45			0.096
b	0.35		0.49	0.013		0.019
b1	0.23		0.32	0.009		0.012
C		0.50			0.020	
c1	45° (typ.)					
D	12.60		13.00	0.496		0.512
E	10.00		10.65	0.393		0.419
e		1.27			0.050	
e3		11.43			0.450	
F	7.40		7.60	0.291		0.299
L	0.50		1.27	0.19		0.050
M			0.75			0.029
S	8° (max.)					



P013L